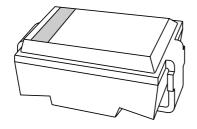
DISCRETE SEMICONDUCTORS

DATA SHEET



BZG01 seriesSMA voltage regulator diodes

Product specification Supersedes data of 2000 Feb 17 2003 Mar 06





SMA voltage regulator diodes

BZG01 series

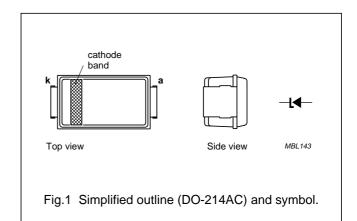
FEATURES

- · Glass passivated
- · High maximum operating temperature
- Ideal for surface mount automotive applications
- · Low leakage current
- · Excellent stability
- UL 94V-O classified plastic package
- Zener working voltage range: 10 to 270 V for 35 types
- Supplied in 12 mm embossed tape and reel, 1500 and 7500 pieces
- Marking: cathode, date code, type name
- · Easy pick and place.

DESCRIPTION

DO-214AC surface mountable package with glass passivated chip.

The well-defined void-free case is of a transfer-moulded thermo-setting plastic. The small rectangular package has two J bent leads.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
P _{tot}	total power dissipation	T _{tp} = 100 °C; see Fig.2	_	2.50	W
		T _{amb} = 25 °C; see Fig.2; device mounted on an Al ₂ O ₃ printed-circuit board: see Fig.5	_	1.50	W
P _{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \mu s$; square pulse; $T_j = 25 \text{ °C}$ prior to surge; see Fig.3	_	150	W
T _{stg}	storage temperature		-65	+175	°C
Tj	junction temperature		-65	+175	°C

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ELECTRICAL CHARACTERISTICS

Total series

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	I _F = 0.1 A; see Fig.4	1.2	V

Per type

 T_j = 25 °C unless otherwise specified.

TYPE No.	WORKING VOLTAGE		DIFFERENTIAL RESISTANCE		TEMPERATURE COEFFICIENT		TEST CURRENT	REVERSE at REVERS	CURRENT E VOLTAGE	
SUFFIX	'	/ _Z (V) at I	z	r _{dif} (Ω	$r_{dif}(\Omega)$ at I_Z $S_Z(\%/K)$ at I_Z		S _Z (%/K) at I _Z		I _R (μ A)	V (V)
(1)	MIN.	NOM.	MAX.	TYP.	MAX.	MIN.	MAX.	I _Z (mA)	MAX.	V _R (V)
C10	9.4	10	10.6	2	7	0.05	0.09	25	80	7.5
C11	10.4	11	11.6	3	8	0.05	0.10	20	40	8.2
C12	11.4	12	12.7	3	9	0.05	0.10	20	20	9.1
C13	12.4	13	14.1	3	10	0.05	0.10	20	10	10
C15	13.8	15	15.6	5	15	0.05	0.10	15	5	11
C16	15.3	16	17.1	5	15	0.06	0.11	15	2	12
C18	16.8	18	19.1	7	20	0.06	0.11	15	1	13
C20	18.8	20	21.2	8	24	0.06	0.11	10	1	15
C22	20.8	22	23.3	8	25	0.06	0.11	10	1	16
C24	22.8	24	25.6	8	25	0.06	0.11	10	1	18
C27	25.1	27	28.9	10	30	0.06	0.11	8	1	20
C30	28	30	32	10	30	0.06	0.11	8	1	22
C33	31	33	35	12	35	0.06	0.11	8	1	24
C36	34	36	38	13	40	0.06	0.11	8	1	27
C39	37	39	41	17	50	0.06	0.11	6	1	30
C43	40	43	46	17	50	0.07	0.12	6	1	33
C47	44	47	50	30	90	0.07	0.12	4	1	36
C51	48	51	54	40	115	0.07	0.12	4	1	39
C56	52	56	60	40	120	0.07	0.12	4	1	43
C62	58	62	66	40	125	0.08	0.13	4	1	47
C68	64	68	72	40	130	0.08	0.13	4	1	51
C75	70	75	79	40	135	0.08	0.13	4	1	56
C82	77	82	87	70	200	0.08	0.13	2.7	1	62
C91	85	91	96	80	250	0.09	0.13	2.7	1	68
C100	94	100	106	120	350	0.09	0.13	2.7	1	75
C110	104	110	116	150	450	0.09	0.13	2.7	1	82
C120	114	120	127	200	550	0.09	0.13	2	1	91
C130	124	130	141	250	700	0.09	0.13	2	1	100
C150	138	150	156	300	1000	0.09	0.13	2	1	110

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TYPE No.	WORKING VOLTAGE		DIFFERENTIAL RESISTANCE		TEMPERATURE COEFFICIENT		TEST CURRENT		CURRENT E VOLTAGE	
SUFFIX	V _Z (V) at I _Z		Z	r _{dif} (Ω) at I _Z		S _Z (%/K) at I _Z		I (m A)	I _R (μ A)	V (A)
(1)	MIN.	NOM.	MAX.	TYP.	MAX.	MIN.	MAX.	I _Z (mA)	MAX.	V _R (V)
C160	153	160	171	350	1100	0.09	0.13	1.5	1	120
C180	168	180	191	400	1200	0.09	0.13	1.5	1	130
C200	188	200	212	500	1500	0.09	0.13	1.5	1	150
C220	208	220	233	700	2250	0.09	0.13	1	1	160
C240	228	240	256	800	2550	0.09	0.13	1	1	180
C270	251	270	289	1000	3000	0.09	0.13	1	1	200

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		30	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	100	K/W
		note 2	150	K/W

Notes

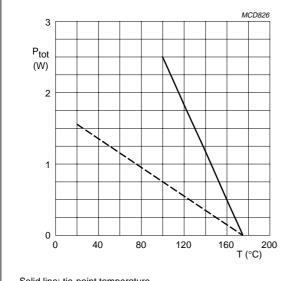
- 1. Device mounted on an Al_2O_3 printed-circuit board, 0.7 mm thick; thickness of Cu-layer \geq 35 μ m, see Fig.5.
- 2. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer ≥40 μm, see Fig.5. For more information please refer to the *'General Part of associated Handbook'*.

^{1.} To complete the type number the suffix is added to the basic type number, e.g. BZG01-C130.

SMA voltage regulator diodes

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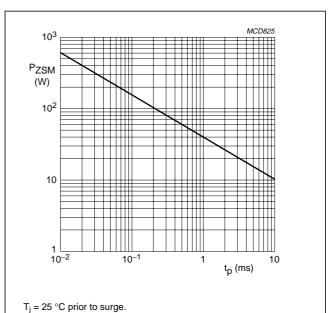
GRAPHICAL DATA



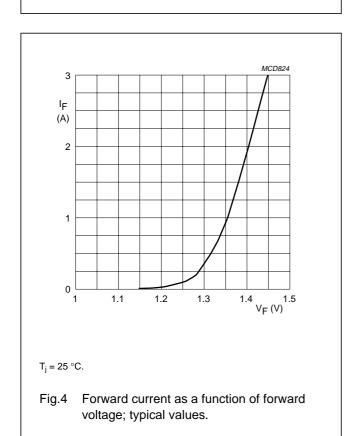
Solid line: tie-point temperature.

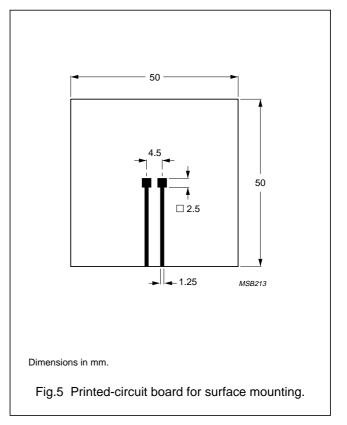
Dotted line: ambient temperature; device mounted on an ${\rm Al}_2{\rm O}_3$ printed-circuit board as shown in Fig.5.

Maximum total power dissipation as a function of temperature.



Maximum non-repetitive peak reverse power dissipation as a function of pulse duration (square pulse).





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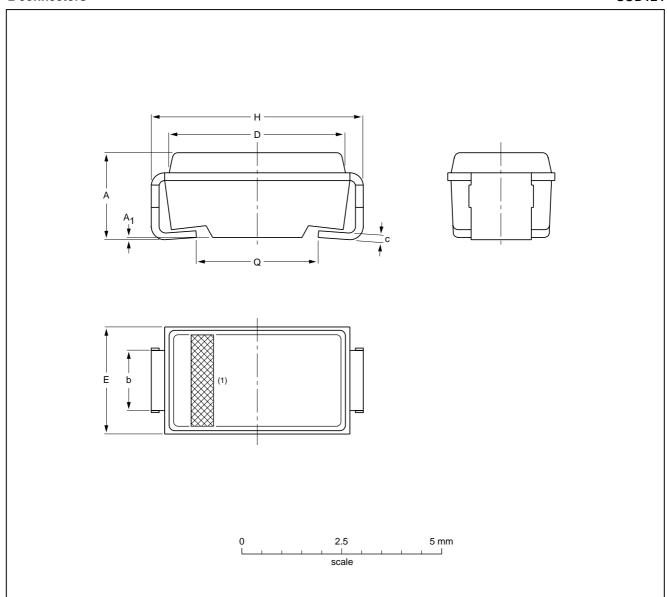
SMA voltage regulator diodes

BZG01 series

PACKAGE OUTLINE

Transfer-moulded thermo-setting plastic small rectangular surface mounted package; 2 connectors

SOD124



DIMENSIONS (mm are the original dimensions)

UNIT	Α	A ₁	b	С	D	E	н	q
mm	2.3 2.0	0.05	1.6 1.4	0.2	4.5 4.3	2.8 2.4	5.5 5.1	3.3 2.7

Note

1. The marking band indicates the cathode.

OUTLINE		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOD124		DO-214AC			99-10-22

SMA voltage regulator diodes

BZG01 series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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